National Semiconductor

54LS38/DM54LS38/DM74LS38 Quad 2-Input NAND Buffers with Open-Collector Outputs

General Description

Connection Diagram

This device contains four independent gates, each of which performs the logic NAND function. The open-collector outputs require external pull-up resistors for proper logical operation.

Features

 Alternate Military/Aerospace device (54LS38) is available. Contact a National Semiconductor Sales Office/ Distributor for specifications.

Pull-Up Resistor Equations

$$R_{MAX} = \frac{V_{CC} (Min) - V_{OH}}{N_1 (I_{OH}) + N_2 (I_{IH})}$$

$$R_{MIN} = \frac{V_{CC} (Max) - V_{OL}}{I_{OL} - N_3 (I_{III})}$$

Where: N_1 (I_{OH}) = total maximum output high current for all outputs tied to pull-up resistor

 N_2 (I_{IH}) = total maximum input high current for all inputs tied to pull-up resistor

 N_3 (I_{IL}) = total maximum input low current for all inputs tied to pull-up resistor



H = High Logic Level

L = Low Logic Level

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Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Output Voltage	7V
Operating Free Air Temperature Range	
DM54LS and 54LS	-55°C to +125°C
DM74LS	0°C to +70°C
Storage Temperature Range	-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	DM54LS38			DM74LS38			Units
		Min	Nom	Max	Min	Nom	Max	Onito
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	v
VIH	High Level Input Voltage	2			2			v
VIL	Low Level Input Voltage			0.7			0.8	v
V _{OH}	High Level Output Voltage			5.5			5.5	v
IOL	Low Level Output Current			12			24	mA
TA	Free Air Operating Temperature	-55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min$, $I_I = -18 \text{ mA}$				-1.5	v
ICEX	High Level Output Current	$V_{CC} = Min, V_O = 5.5V$ $V_{IL} = Max$				250	μΑ
V _{OL} Low Level Output Voltage	Low Level Output	$V_{CC} = Min, I_{OL} = Max$	DM54		0.25	0.4	
	V _{IH} = Min	DM74		0.35	0.5	v	
	$I_{OL} = 12 \text{ mA}, V_{CC} = \text{Min}$	DM74		0.25	0.4		
ų	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 7V$				0.1	mA
Iн	High Level Input Current	$V_{CC} = Max, V_1 = 2.7V$				20	μΑ
Ι _{ΙL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$				-0.36	mA
Іссн	Supply Current with Outputs High	V _{CC} = Max			0.9	2	mA
ICCL	Supply Current with Outputs Low	V _{CC} = Max			6	12	mA

Switching Characteristics at $V_{CC} = 5V$ and $T_A = 25^{\circ}C$ (See Section 1 for Test Waveforms and Output Load)

Parameter					
	C _L =	45 pF	C _L =	Units	
	Min	Max	Min	Max	
Propagation Delay Time Low to High Level Output		22		48	ns
Propagation Delay Time High to Low Level Output		22		29	ns
	Propagation Delay Time Low to High Level Output Propagation Delay Time	Min Propagation Delay Time Low to High Level Output Propagation Delay Time	Parameter CL = 45 pF Min Max Propagation Delay Time 22 Propagation Delay Time 22	Min Max Min Propagation Delay Time 22 Propagation Delay Time 22	Parameter CL = 45 pF CL = 150 pF Min Max Min Max Propagation Delay Time Low to High Level Output 22 48 Propagation Delay Time 22 29

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